Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
Between 0.170 inches and 0.210 inches	
Terminal Length:	
Between 0.500 inches and 0.750 inches	
Overall Diameter:	
Between 0.209 inches and 0.230 inches	
End Application:	
Helicopter, seahawk, h-60; aircraft, starlifter c-141; aircraft, viking s-3b; seasprite helicopter; seaking	g helicopter; lamps mark iii, sh-60b
helicopter; prowler ea-6b aircraft; ta-4j aircraft; c-130 hercules; p-3 orion	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Burn in and hermetically sealed case	
Criticality Code Justification:	
Feat	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
-50.0 gate to source voltage all transistor	
Current Rating Per Characteristic:	
50.00 milliamperes gate current all transistor	
Power Rating Per Characteristic:	
500.0 milliwatts total power dissipation all transistor	
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius ambient air	
Special Features:	
Weapon system essential	
Terminal Type And Quantity:	
6 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
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Demilitarization:	
No	
Fiig:	
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